IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Walker, Darryl G.

Serial No.: N/A

Filed: Herewith

Title (As Amended): Random Access
 Memory Cell Having Reduced Current
 Leakage and Having a Pass Transistor
 Control Gate Formed in a Trench

Attorney Docket No.: W-0002D3

PRELIMINARY AMENDMENT

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450

Dear Sir:

Alexandria, VA 22313

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The following Preliminary Amendment is submitted in conjunction with a newly filed Continuation Patent Application claiming priority from co-pending parent Patent Application 09/546,747 entitled Random Access Memory Cell Having Reduced Current Leakage.

Entry of the following preliminary amendments is respectfully requested.

I hereby certify that this correspondence is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR §1.10 on the date indicated below and is addressed to:

Mail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313.

Date of Deposit: 9/29/03 Express Mail Label No.: EU/83 238 765 US

Typed Name: Bradley T. Sako
Signature: